## LV58063MC

## Bi-CMOS IC Step-down Switching Regulator



http://onsemi.com

#### Overview

LV58063MC is a 1ch step-down switching regulator.  $0.13\Omega$  FET is incorporated on the upper side to achieve high-efficiency operation for large output current.

Low-heat resistance and compact-package SOP8L (200mil) employed.

Current mode control gives superior load current response with easy phase compensation.

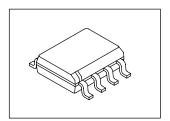
EN pin, allowing the standby mode with the current drain of 70μA.

Pulse-by-pulse over-current protection and overheat protection available for protection of load devices.

Externally adjustable soft start time.

#### **Function**

- 3A 1ch step-down switching regulator
- Thermal shutdown
- Wide input range (8 to 28V)
- Reference voltage: 0.8V
- High efficiency (90% I<sub>OUT</sub>=1A, V<sub>IN</sub>=12V, V<sub>OUT</sub>=5V)
- Fixed frequency: 370kHz
- Standby mode
- Soft start
- Over-current protection
- Compact package: SOP8L (200mil) with exposed pad
- Overshoot control after over-current protection event



SOP8L (200mil)

## **Application**

- LCD/PDP-TV
- STB
- White Goods
- Office equipment
- General consumer electronics

#### ORDERING INFORMATION

See detailed ordering and shipping information on page 6 of this data sheet.

## **Specifications**

### **Absolute Maximum Ratings** at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum input V <sub>IN</sub> voltage	V <sub>IN</sub> max		32	V
BOOT pin maximum voltage	V <sub>BT</sub> max		37	V
SW pin maximum voltage	V <sub>SW</sub> max		V <sub>IN</sub> max	٧
BOOT pin-SW pin maximum voltage	V <sub>BS-SW</sub> max		7	V
FB, EN, COMP, SS pin maximum	Vfs max		7	V
voltage				
Allowable power dissipation	Pd max	Mount on a specified board *	2.05	W
Junction temperature	Tj max		150	°C
Operating temperature	Topr		-20 to +80	°C
Storage temperature	Tstg		-40 to +150	°C

<sup>\*</sup> Specified board:  $46.4 \text{mm} \times 31.8 \text{mm} \times 1.7 \text{mm}$ , glass epoxy.

Note: Plan the maximum voltage while including coil and surge voltages, so that the maximum voltage is not exceeded even for an instant.

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### **Recommended Operating Conditions** at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
V <sub>IN</sub> pin voltage	VIN		8 to 28	V
BOOT pin voltage	V <sub>BT</sub>		-0.3 to 34	V
SW pin voltage	V <sub>SW</sub>		-0.4 to V <sub>IN</sub>	V
BOOT pin-SW pin voltage	V <sub>BS-SW</sub>		6.5	V
FB, EN, COMP, SS pin voltage	V <sub>FSO</sub>		6	V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

## **Electrical Characteristics** at $Ta = 25^{\circ}C V_{IN} = 12V$ , unless otherwise specified.

	0 1 1	Symbol Conditions	Ratings			
Parameter	Symbol		min	typ	max	Unit
IC current drain in standby	I <sub>CC</sub> 1	EN=0V		70		μΑ
IC current drain in operation	I <sub>CC</sub> 2	EN=open, FB=1V		5		mA
fficiency Effcy V <sub>IN</sub> =12V, I <sub>OUT</sub> =1A, V <sub>OUT</sub> =5V Design target: *1			90		%	
Reference voltage	Vref	V <sub>IN</sub> =8V to 28V (±2%)	-2%	0.8	+2%	V
FB pin bias current	Iref	FB=0.8V application		10	100	nA
High-side ON resistance	RonH	BOOT=5V		0.13		Ω
Low-side ON resistance	RonL			7		Ω
Oscillation frequency	Fosc		296	370	444	kHz
Oscillation frequency during short-circuit protection	Foscs		30	38	46	kHz
EN high-threshold voltage	Venh				1.9	V
EN low-threshold voltage	Venl		0.8			V
EN pull-up corrent	len	EN=0V		16		μА
Maximum ON DUTY	D max			80		%
Current limit peak value	Icl	V <sub>IN</sub> =12V, V <sub>OUT</sub> =5V, L=10μH	3.8			Α
Thermal shutdown temperature	Ttsd	*Design guarantee *2		160		°C
Thermal shutdown temperature hysteresis	Dtsd	*Design guarantee *2		40		°C
Soft start current	ISS	SS=0V	6	10	14	μА

<sup>\*1:</sup> Design target (not tested before shipment)

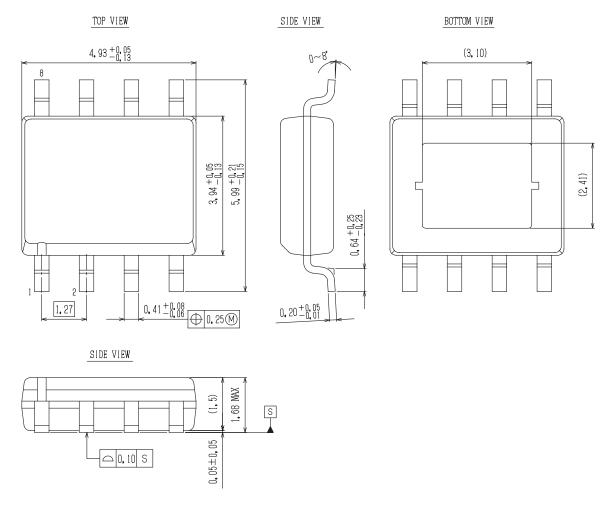
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

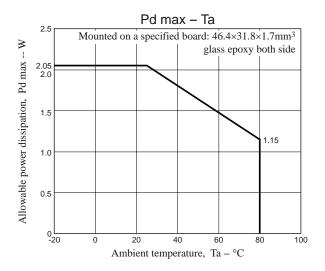
<sup>\*2:</sup> Design guarantee (value guaranteed by design and not tested before shipment)

## **Package Dimensions**

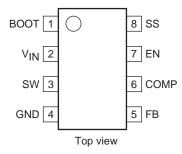
unit: mm

# SOIC8 N EP / SOP8L (200 mil) CASE 751DM ISSUE O

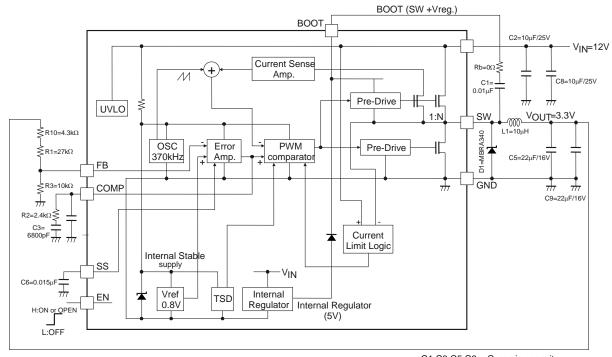




## **Pin Assignment**



## **Block Diagram and Sample Application Circuit (3.3V output)**



- C1,C8,C5,C9 = Ceramic capacitor L1=CDRH105RNP-100NC (sumida)

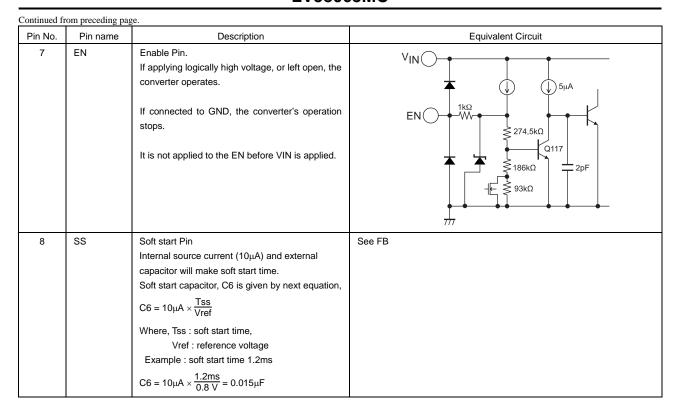
## LV58063MC

## Pin Function

Pin No.	Pin name	Description	Equivalent Circuit
1	BOOT	Internal high side mos fet boot strap capacitor	
	8001	Pin.  Connect around $0.01\mu F$ capacitor or greater between SW and BOOT.  To operate within absolute maximum rating of SW, to keep stable operation, and to reduce switching noise, please use a series resistor, Rb (value is around $100\Omega$ ) is recommended to use.	BOOT  Hi side MOS  SW  Low side MOS
2	VIN	Input Voltage Pin.  Large Filter Capacitor ( equal or larger than 20μF) should be connected between V <sub>IN</sub> and GND to eliminate noise on the input and to operate properly.  When using electrolytic capacitors, it is recommended to add a ceramic capacitor of about 0.4 μF between VIN CND for stability.	See BOOT
3	SW	about 0.1uF between VIN-GND for stability.  Power Switching Pin.  Connect the output LC filter.  Connect the above-mentioned capacitor between this pin and BOOT pin.	See BOOT
4	GND	Ground pin.	
5	FB	Feedback pin. Connect a voltage divider resistor across FB to set the regulated output voltage. The output voltage is given by next equation. $V_{OUT} = Vref \times \left\{1 + \frac{(R1 + R10)}{R3}\right\}$ $Vref = 0.8V$ Example: 3.3V output voltage (See Block Diagram and Sample Application Circuit) $V_{OUT} = 0.8 \times \left\{1 + \frac{(27k + 4.3k)}{10k}\right\}$ =3.304V	VIN Internal regulated  10µA  FB  NREF  0.8V
6	COMP	Phase compensation pin.  Connect an external capacitor and a resistor for the DC DC converter close loop-phase compensation.	COMP Clump circuit

Continued on next page.

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## Considerations for the design

- Insertion of serial beads in the Schottky diode for removal of noise may cause generation of the negative voltage on SW pin deviating from the absolute maximum rating at the SW pin, resulting in failure of normal operation. Please, do not insert beads as above described. Instead, remove noise by Rb resistor.
- Exposed pad on the bottom side of the IC should be soldered. We cannot recommend other usages of the exposed pad.

## **ORDERING INFORMATION**

Device	Package	Shipping (Qty / Packing)	
LV58063MC-AH	SOP8L (200mil) (Pb-Free / Halogen Free)	2000 / Tape & Reel	
LV58063MCZ-AH	SOP8L (200mil) (Pb-Free / Halogen Free)	2000 / Tape & Reel	

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